



#### NPN SURFACE MOUNT SMALL SIGNAL TRANSISTOR IN SOT23

#### **Features**

- Ideally Suited for Automatic Insertion
- Complementary PNP Types Available (BC856 BC858)
- For switching and AF Amplifier Applications
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

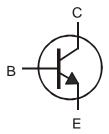
### **Mechanical Data**

- Case: SOT-23
- UL Flammability Rating 94V-0
- Case material: molded Plastic "Green" Compound
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.008 grams (Approximate)

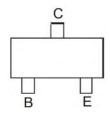
SOT23







Device Symbol



Top View Pin-Out

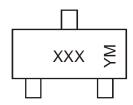
### Ordering Information (Note 3 & 4)

Product	Marking	Reel size (inches)	Quantity per reel
BC846A-7-F	K1Q	7	3,000
BC846B-7-F	K1R	7	3,000
BC846BQ-7-F	K1R	7	3,000
BC846B-13-F	K1R	13	10,000
BC847A-7-F	K1Q	7	3,000
BC847AQ-7-F	K1Q	7	3,000
BC847A-13-F	K1Q	13	10,000
BC847B-7-F	K1R	7	3,000
BC847BQ-7-F	K1R	7	3,000
BC847B-13-F	K1R	13	10,000

Product	Marking	Reel size (inches)	Quantity per reel
BC847C-7-F	K1M	7	3,000
BC847C-13-F	K1M	13	10,000
BC848A-7-F	K1Q	7	3,000
BC848B-7-F	K1R	7	3,000
BC848B-13-F	K1R	13	10,000
BC848C-7-F	K1M	7	3,000
BC848CQ-7-F	K1M	7	3,000

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com
- 3. Tape width is 8mm. For more packaging details, go to our website at http://www.diodes.com.
  4. Products with Q-suffix are automotive grade. All other products are commercial grade.

## **Marking Information**



XXX = Product Type Marking Code, YM = Date Code Marking Y = Year ex: X = 2010M = Month ex: 9 = September

#### Date Code Key

Year	2010	20	011	2012	2	2013	2014		2015	2016		2017
Code	Χ		Υ	Z		Α	В		С	D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

BC846A - BC848C Document Number: DS11108 Rev. 23 - 2



## Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Character	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V <sub>CBO</sub>	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V <sub>CEO</sub>	45	V
	BC848		30	
Emitter-Base Voltage	BC846, BC847	V	6.0	V
Emilier-base voltage	BC848	V <sub>EBO</sub>	5.0	V
Continuous Collector Current		Ic	100	mA
Peak Collector Current		I <sub>CM</sub>	200	mA
Peak Emitter Current		I <sub>EM</sub>	200	mA

## Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	$P_{D}$	300	mW
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	417	°C/W
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-65 to +150	°C

Notes:

5. For a device surface mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air conditions; the device is measured when operating in a steady-state condition.



# Electrical Characteristics @TA = 25°C unless otherwise specified

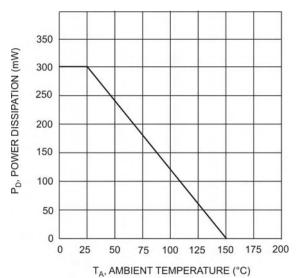
Characteristic			Symbol	Min	Тур	Max	Unit	Test Condition	
BC846			80						
Collector-Base Breakdown Voltage		BC847	BV <sub>CBO</sub>	50	-	-	V	$I_C = 10\mu A$	
	•	BC848		30				-	
0 11 1 5 11 5 11	\ / L	BC846		65		-	V		
Collector-Emitter Breakdown	Voltage	BC847	BV <sub>CEO</sub>	45	-			$I_C = 10mA$	
(Note 6)		BC848	020	30	1				
Freitter Bees Breekdeur Va	14	BC846 / BC847	D) /	6		_	.,	1 4 .	
Emitter-Base Breakdown Vo	itage	BC848	BV <sub>EBO</sub>	5	-	-	V	$I_E = 1\mu A$	
Collector Cutoff Current			I <sub>CBO</sub>	_	_	15	μA	V <sub>CB</sub> = 40V	
Collector Cutoff Current			iCBO	,	_	5	μΛ	V <sub>CB</sub> = 30V, T <sub>A</sub> =150°C	
		BC846				15		V <sub>CE</sub> = 80V	
Collector Emitter Cutoff Curr	ent	BC847	I <sub>CES</sub>	-	-	15	nA	V <sub>CE</sub> = 50V	
		BC848				15		V <sub>CE</sub> = 30V	
Small Signal Current Gain	BC846A / E	3C847A / BC848A			200				
(Note 6)	BC846B / E	3C847B / BC848B	h <sub>fe</sub>	-	330	-	-		
(Note 6)	BC847	7C / BC848C			600				
Input Impedance	BC846A / E	3C847A / BC848A			2.7			1	
(Note 6)	BC846B / E	BC846B / BC847B / BC848B		-	4.5	-	kΩ		
(Note 6)	BC847	7C / BC848C	h <sub>ie</sub>		8.7			$I_{C} = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
Outrout Admitton	BC846A / BC847A / BC848A		h <sub>oe</sub>	1	18		μS	f=1.0kHz	
Output Admittance (Note 6)	BC846B / BC847B / BC848B				30	-			
(Note 6)	BC847C / BC848C				60				
Davieras Valtera Transfer	BC846A / E	3C847A / BC848A			1.5x10 <sup>-4</sup>			l l	
Reverse Voltage Transfer Ratio (Note 6)	BC846B / E	BC846B / BC847B / BC848B		-	2x10 <sup>-4</sup>	-	-		
Kallo (Note 6)	BC847	7C / BC848C	h <sub>re</sub>		3x10 <sup>-4</sup>				
	BC846A / E	3C847A / BC848A		110	180	220			
DC Current Gain (Note 6)	BC846B / E	C847B / BC848B	h <sub>FE</sub>	200	290	450	-	$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
		7C / BC848C		420	520	800			
Collector-Emitter Saturation	Voltage		V <sub>CE(sat)</sub>	_	90	250	mV	$I_C = 10mA, I_B = 0.5mA$	
(Note 6)			VCE(sat)		200	600	111.0	$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Turn-On Voltag	re(Note 6)		V <sub>BE(on)</sub>	580	660	700	mV	$I_C = 2mA$ , $V_{CE} = 5V$	
Base-Emilier Turn-On Voltag	JC(1401C 0)		vBE(on)	-	-	770	1117	$I_C = 10$ mA, $V_{CE} = 5$ V	
Base-Emitter Saturation Volt	age(Note 6)		V <sub>BE(sat)</sub>	_	700	_	mV	$I_C = 10 \text{mA}, I_B = 0.5 \text{mA}$	
Base-Emitter Saturation Voltage(Note 6)			VBE(sat)		900		1117	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$	
Output Capacitance		$C_{obo}$	-	3	-	pF	V <sub>CB</sub> = 10V, f = 1.0MHz		
Transition Frequency		f <sub>T</sub>	100	300	-	MHz	$V_{CE} = 5V$ , $I_C = 10mA$ , $f = 100MHz$		
Noise Figure			NF	-	2	10	dB	$V_{CE}$ =5V, $I_{C}$ =200 $\mu$ A $R_{S}$ =2 $k\Omega$ , f=1 $k$ Hz $\Delta$ f=200Hz	

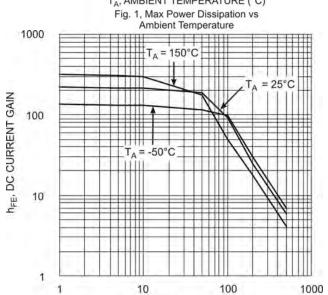
Note:

6. Short duration pulse test used to minimize self-heating effect.

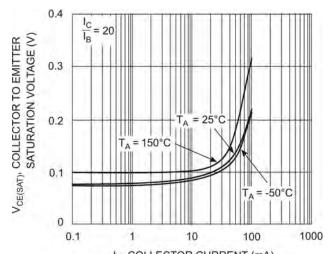


# **Typical Electrical Characteristics**



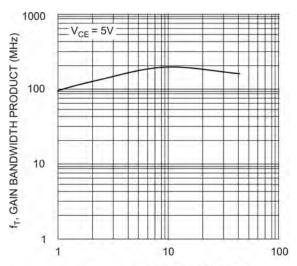


I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs. Collector Current



I<sub>C</sub>, COLLECTOR CURRENT (mA)

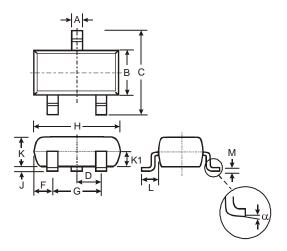
Fig. 2 Collector Emitter Saturation Voltage
vs. Collector Current



I<sub>C</sub>, COLLECTOR CURRENT (mA)
Fig. 4, Gain Bandwidth Product vs Collector Current

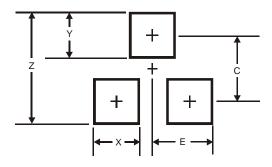


# **Package Outline Dimensions**



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.903	1.10	1.00					
<b>K</b> 1	-	-	0.400					
L	0.45	0.61	0.55					
M	0.085	0.18	0.11					
α	0°	8°	-					
All	Dimens	ions in	mm					

# Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
Е	1.35



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